



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

ECH8674 — P-Channel Silicon MOSFET General-Purpose Switching Device Applications

Features

- 1.8V drive
- Composite type, facilitating high-density mounting
- Halogen free compliance
- Protection diode in

Specifications

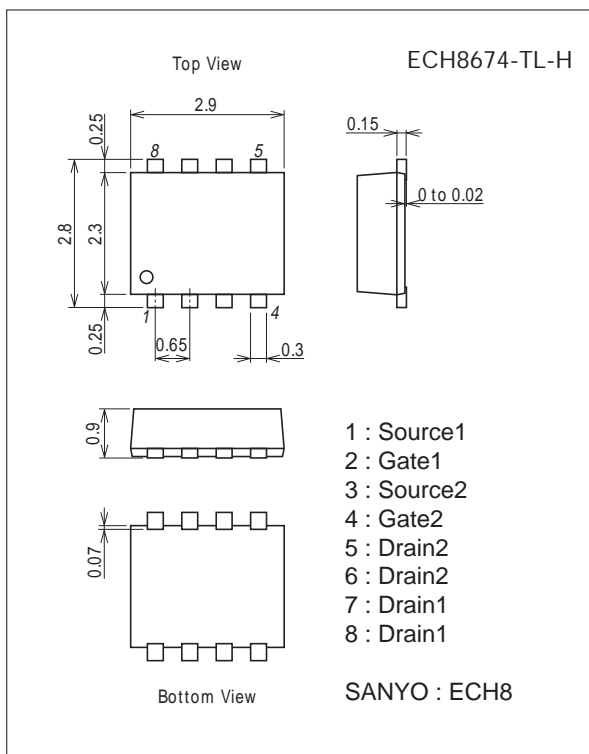
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-12	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	I _D		-5	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycles≤1%	-30	A
Allowable Power Dissipation	P _D	When mounted on ceramic substrate (1200mm ² ×0.8mm) 1unit	1.3	W
Total Power Dissipation	P _T	When mounted on ceramic substrate (1200mm ² ×0.8mm)	1.5	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Package Dimensions

unit : mm (typ)

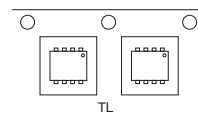
7011A-001



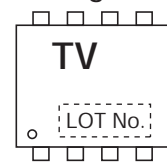
Product & Package Information

- Package : ECH8
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

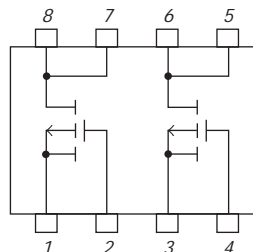
Packing Type : TL



Marking



Electrical Connection

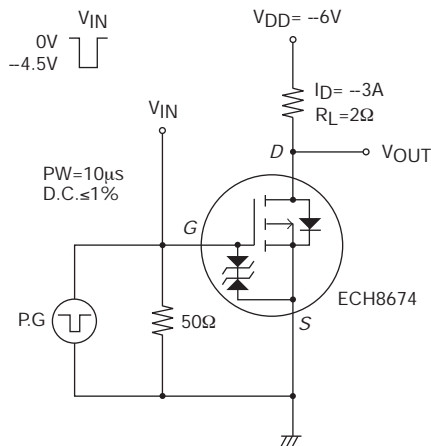


ECH8674

Electrical Characteristics at Ta=25°C

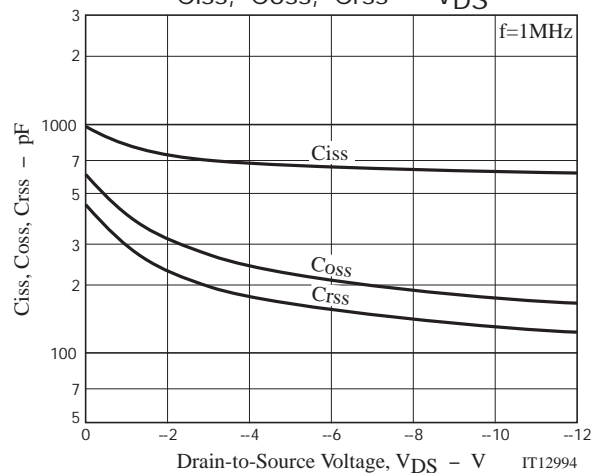
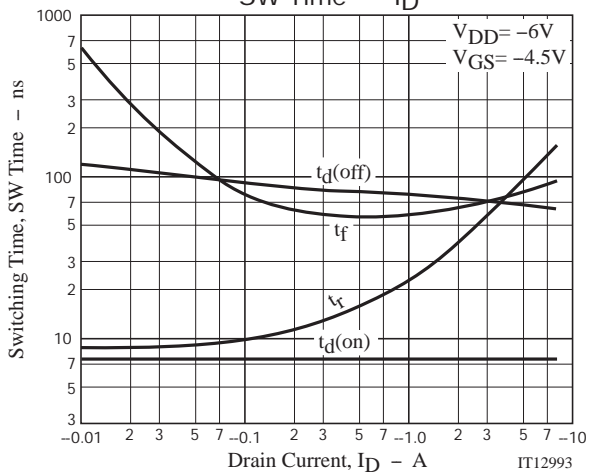
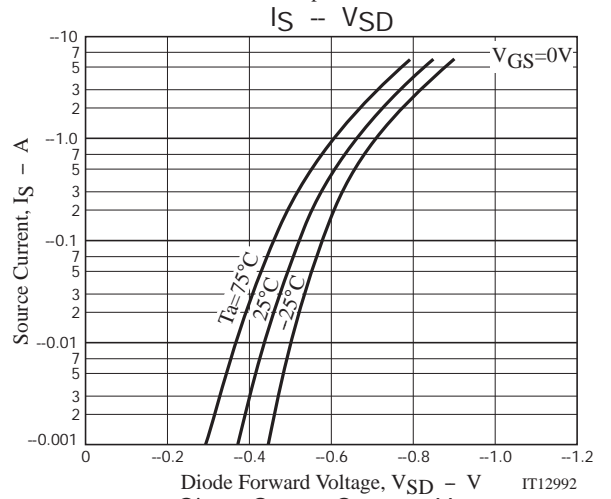
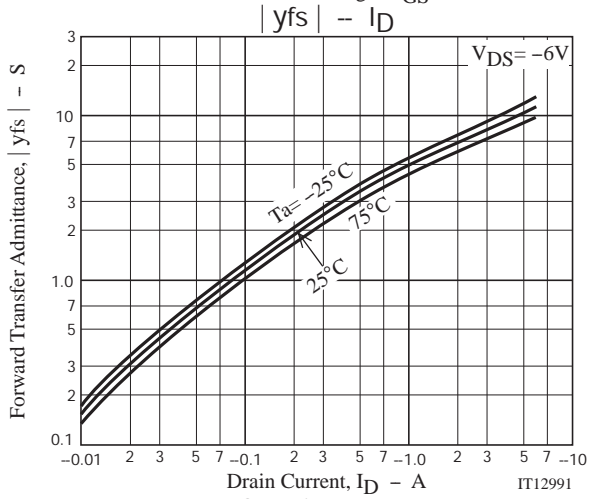
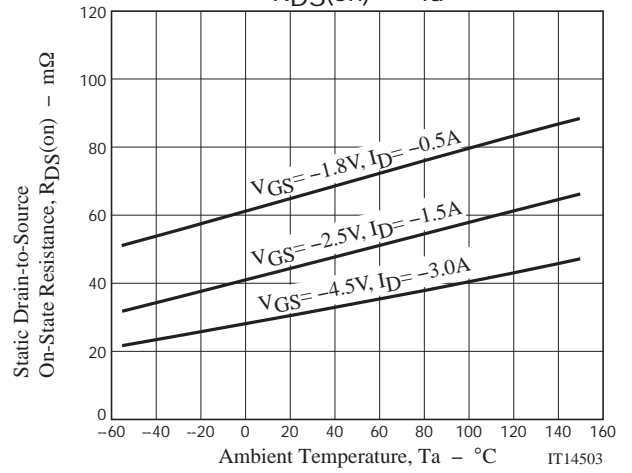
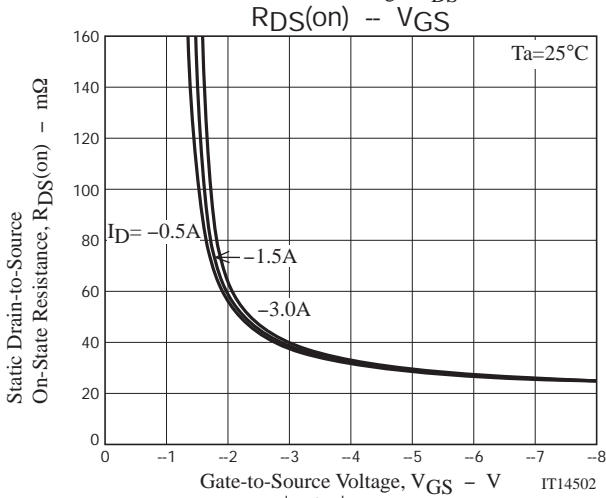
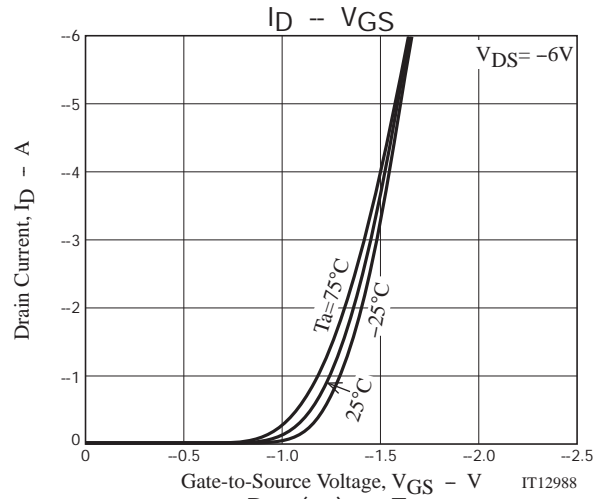
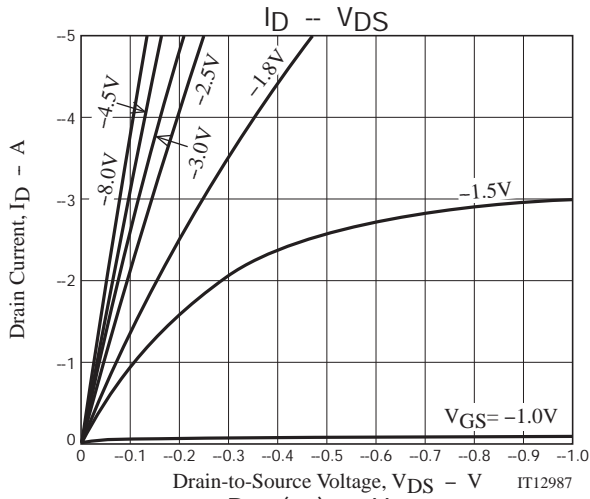
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-12			V
Zero-Gate Voltage Drain Current	IDSS1	VDS=-8V, VGS=0V			-1	μA
	IDSS2	VDS=-12V, VGS=0V			-10	μA
Gate-to-Source Leakage Current	IGSS	VGS=±8V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=-6V, ID=-1mA	-0.4		-1.3	V
Forward Transfer Admittance	yfs	VDS=-6V, ID=-3A	4.8	8.1		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=-3A, VGS=-4.5V		31	41	mΩ
	RDS(on)2	ID=-1.5A, VGS=-2.5V		45	63	mΩ
	RDS(on)3	ID=-0.5A, VGS=-1.8V		66	95	mΩ
Input Capacitance	Ciss	VDS=-6V, f=1MHz		660		pF
Output Capacitance	Coss			210		pF
Reverse Transfer Capacitance	Crss			155		pF
Turn-ON Delay Time	t _{d(on)}			7.4		ns
Rise Time	t _r	See specified Test Circuit.		57		ns
Turn-OFF Delay Time	t _{d(off)}			72		ns
Fall Time	t _f			69		ns
Total Gate Charge	Qg			6.9		nC
Gate-to-Source Charge	Qgs	VDS=-6V, VGS=-4.5V, ID=-5A		1.2		nC
Gate-to-Drain "Miller" Charge	Qgd			1.8		nC
Diode Forward Voltage	VSD		IS=-5A, VGS=0V		-0.83	-1.2

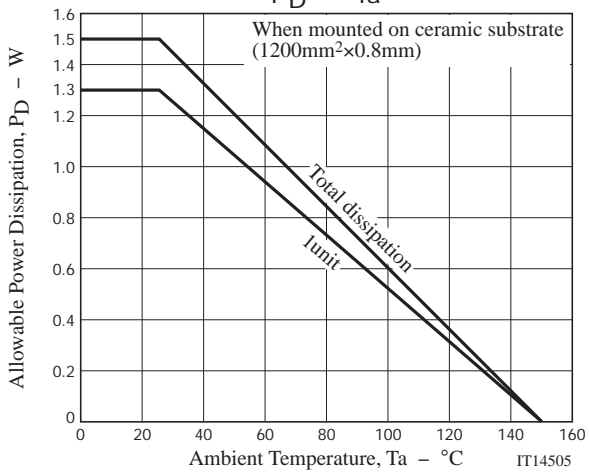
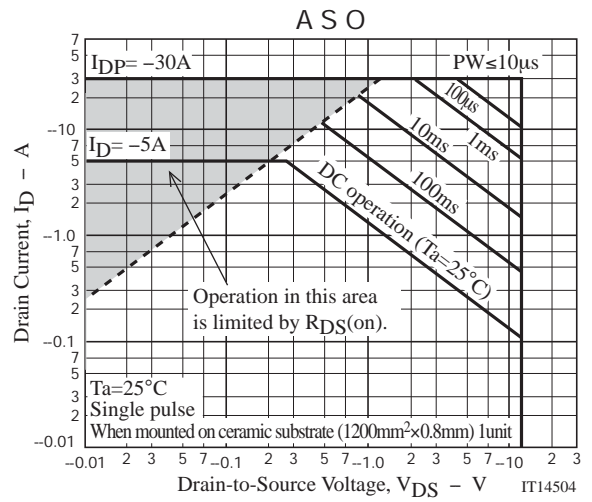
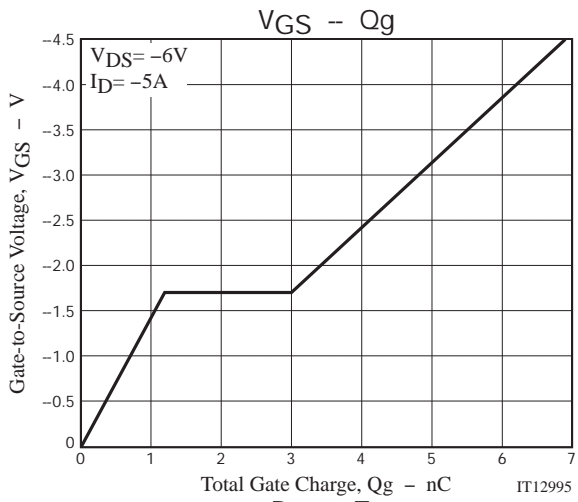
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
ECH8674-TL-H	ECH8	3,000pcs./reel	Pb Free and Halogen Free





Embossed Taping Specification

ECH8674-TL-H

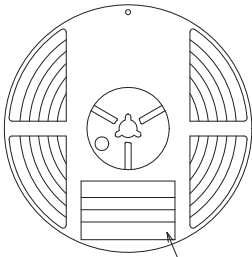
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
ECH8	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label
(unit :mm)

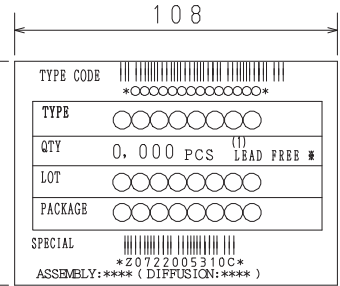
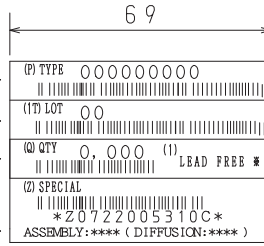
Outer box label
It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Reel label

Type No.
LOT No.
Quantity
Origin



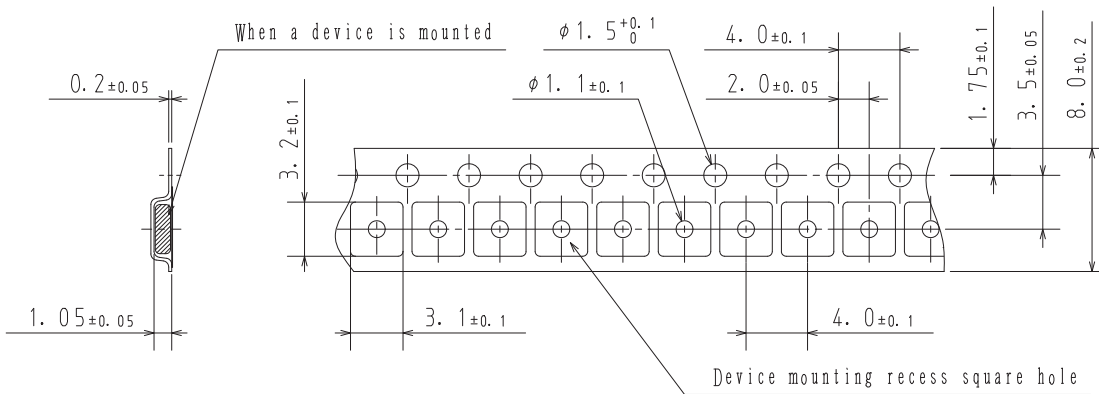
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

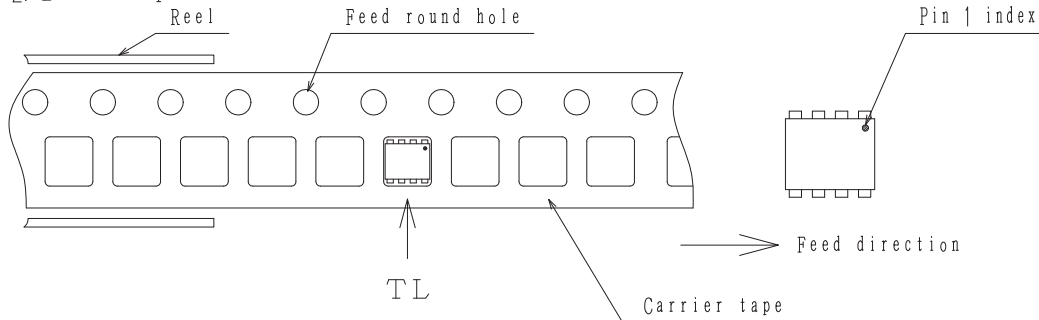
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction



Those with pin 1 index on the feed hole side.....TL

Note on usage : Since the ECH8674 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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